



DCR2950W65

Phase Control Thyristor

DS5871-4 April 2013 (LN30265)

FEATURES

- Double Side Cooling
- High Surge Capability

APPLICATIONS

- High Power Drives
- High Voltage Power Supplies
- Static Switches

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V _{DRM} and V _{RRM} V	Conditions
DCR2950W65* DCR2950W60 DCR2950W55 DCR2950W50	6500 6000 5500 5000	$\begin{split} T_{vj} &= \text{-}40^{\circ} \text{ C to } 125^{\circ} \text{ C,} \\ I_{DRM} &= I_{RRM} = 300\text{mA,} \\ V_{DRM}, V_{RRM} t_p = 10\text{ms,} \\ V_{DSM} \& V_{RSM} = \\ V_{DRM} \& V_{RRM} + 100V \\ respectively \end{split}$

Lower voltage grades available. * 6200V @ -40⁰ C, 6500V @ 0⁰ C

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DCR2950W65

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

KEY PARAMETERS

V_{DRM}	6500V
$I_{T(AV)}$	2945A
I _{TSM}	38500A
dV/dt*	1500V/μs
dI/dt	300A/μs

* Higher dV/dt selections available

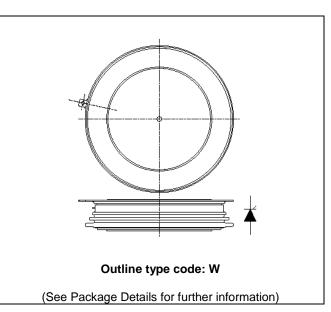


Fig. 1 Package outline





CURRENT RATINGS

T_{case} = 60° C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Si	de Cooled			
I _{T(AV)}	Mean on-state current	Half wave resistive load	2945	А
I _{T(RMS)}	RMS value	-	4629	А
I _T	Continuous (direct) on-state current	-	4430	А

SURGE RATINGS

Symbol Parameter		Test Conditions	Max.	Units
I _{TSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 125° C	38.85	kA
l ² t	I ² t for fusing	$V_R = 0$	7.55	MA ² s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions	Min.	Max.	Units	
R _{th(j-c)}	Thermal resistance – junction to case	Double side cooled	Double side cooled DC		0.00631	° C/W
		Single side cooled	Single side cooled Anode DC		0.01115	° C/W
			Cathode DC	-	0.01453	° C/W
R _{th(c-h)}	Thermal resistance – case to heatsink	Clamping force 76.0kN Double side		-	0.0014	° C/W
		(with mounting compound)	Single side	1	0.0028	° C/W
T_{vj}	Virtual junction temperature	Blocking V _{DRM} / _{VRRM}		-	125	°C
T _{stg}	Storage temperature range			-55	125	°C
F _m	Clamping force			68.0	84.0	kN





DYNAMIC CHARACTERISTICS

Symbol	Parameter	Test Conditio	Test Conditions		Max.	Units
I _{RRM} /I _{DRM}	Peak reverse and off-state current	At V _{RRM} /V _{DRM} , T _{case} = 125° C		-	300	mA
dV/dt	Max. linear rate of rise of off-state voltage	To 67% V _{DRM} , T _j = 125° C, g	ate open	-	1500	V/µs
dI/dt	Rate of rise of on-state current	From 67% V _{DRM} to 2x I _{T(AV)}	Repetitive 50Hz	-	150	A/µs
		Gate source 30V, 10Ω,	Non-repetitive	-	300	A/µs
		$t_r < 0.5 \mu s, T_j = 125^{\circ} C$				
V _{T(TO)}	Threshold voltage – Low level	500 to 2400A at T _{case} = 125°	С	-	0.94	V
	Threshold voltage – High level	2400 to 7200A at T _{case} = 125° C		-	1.13	V
r _T	On-state slope resistance – Low level	500A to 2400A at T _{case} = 125° C		-	0.343	mΩ
	On-state slope resistance – High level	2400A to 7200A at T _{case} = 125° C		-	0.264	mΩ
t _{gd}	Delay time	$V_D = 67\% V_{DRM}$, gate source 30V, 10Ω		-	3	μs
	,	$t_r = 0.5 \mu s, T_j = 25^{\circ} C$				
tq	Turn-off time	$T_j = 125^{\circ} \text{ C}, V_R = 200 \text{V}, dI/dt$	= 1A/µs,	-	1200	μs
		dV _{DR} /dt = 20V/μs linear				
Qs	Stored charge	$I_T = 2000A$, $T_j = 125^{\circ}$ C, $dI/dt - 1A/\mu s$,		2800	6400	μC
ال	Latching current	$T_j = 25^{\circ} \text{ C}, V_D = 5V$		-	3	А
I _H	Holding current	$T_j = 25^{\circ} \text{ C}, R_{G-K} = \infty, I_{TM} = 50$	00A, I _T = 5A	-	300	mA





GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
V_{GT}	Gate trigger voltage	$V_{DRM} = 5V$, $T_{case} = 25^{\circ}$ C	1.5	V
V_{GD}	Gate non-trigger voltage	At 50% V _{DRM} , T _{case} = 125°C	0.4	V
I _{GT}	Gate trigger current	$V_{DRM} = 5V$, $T_{case} = 25^{\circ}$ C	400	mA
I _{GD}	Gate non-trigger current	At 50% V _{DRM} , T _{case} = 125°C	15	mA

CURVES

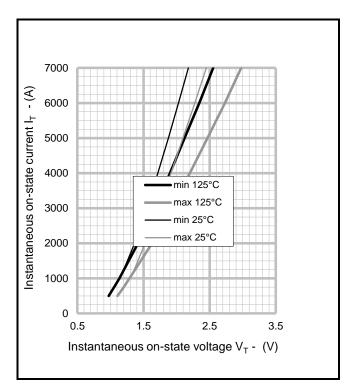


Fig.2 Maximum & minimum on-state characteristics

V_{TM} EQUATION

 $V_{TM} = A + Bln (I_T) + C.I_T + D.\sqrt{I_T}$

Where A = 0.914146

B = -0.03808

C = 0.00016

D = 0.015311

these values are valid for T_j = 125° C for I_T 500A to 7200A

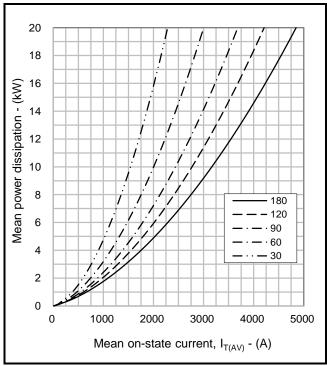


Fig.3 On-state power dissipation - sine wave

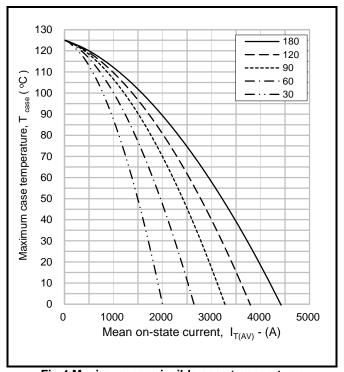


Fig.4 Maximum permissible case temperature, double side cooled – sine wave

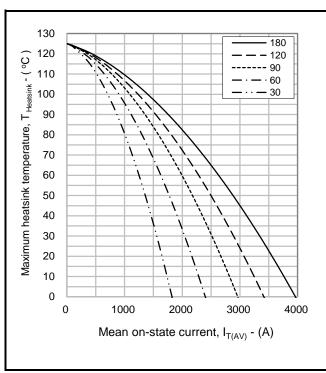


Fig.5 Maximum permissible heatsink temperature, double side cooled – sine wave

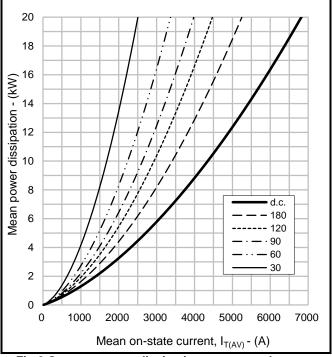
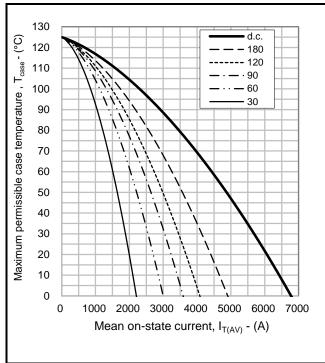
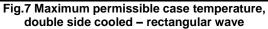


Fig.6 On-state power dissipation - rectangular wave





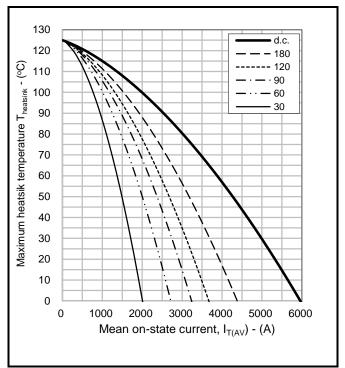
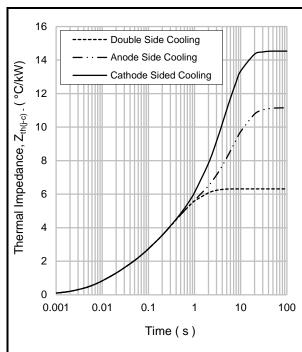


Fig.8 Maximum permissible heatsink temperature, double side cooled – rectangular wave



		1	2	3	4
Double side cooled	R _i (°C/kW)	0.8816	1.2993	2.8048	1.3305
	T _i (s)	0.0106818	0.058404	0.3584979	1.1285
Anode side cooled	R _i (°C/kW)	1.5197	3.2398	5.7622	0.6312
	T _i (s)	0.0170581	0.2424644	6.013	15.364
Cathode side cooled	R _i (°C/kW)	1.4106	2.4667	6.7451	3.9054
	T _i (s)	0.0158344	0.1786951	3.6201	6.196

 $Z_{th} = \sum [R_i x (1-exp. (t/t_i))]$ [1]

 $\Delta R_{\text{th(j-c)}}$ Conduction

Tables show the increments of thermal resistance $R_{\text{th(j-c)}}$ when the device operates at conduction angles other than d.c.

	Double side cooling			Anode Side Cooling			
	$\Delta Z_{th}(z)$				ΔZ_1	th (z)	
θ°	sine.	rect.		θ°	sine.	rect.	
180	1.00	0.67		180	0.94	0.64	
120	1.16	0.97		120	1.08	0.91	
90	1.33	1.13		90	1.23	1.06	
60	1.48	1.31		60	1.37	1.22	
30	1.61	1.51		30	1.47	1.38	
4.5	4.00	4 64		4.5	1 0	4 4	

Cathode Sided Cooling					
	ΔZ_{th} (z)				
θ°	sine. rect.				
180	0.95	0.65			
120	1.09	0.92			
90	1.25	1.07			
60	1.38	1.23			
30	1.49	1.40			
15	1 5 /	1 40			

Fig.9 Maximum (limit) transient thermal impedance - junction to case (° C/kW)

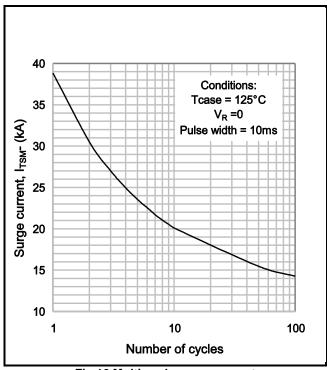


Fig.10 Multi-cycle surge current

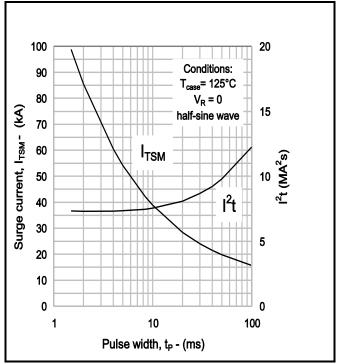


Fig.11 Single-cycle surge current

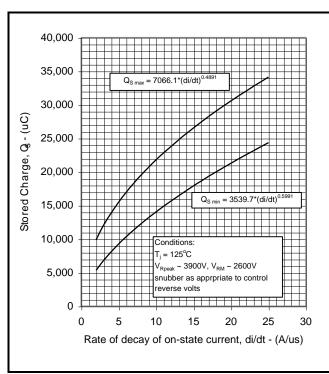


Fig.10 Reverse recovery charge

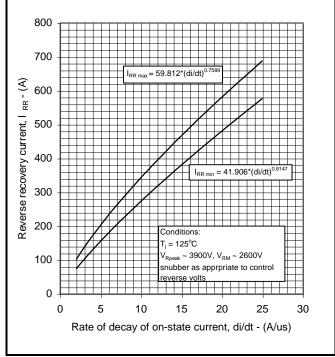


Fig.11 Reverse recovery current

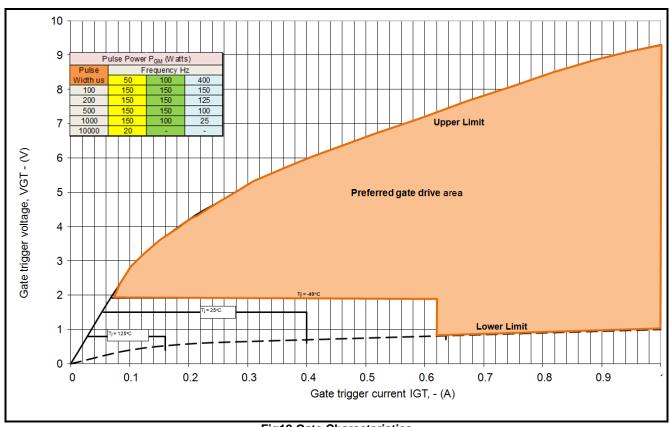


Fig12 Gate Characteristics

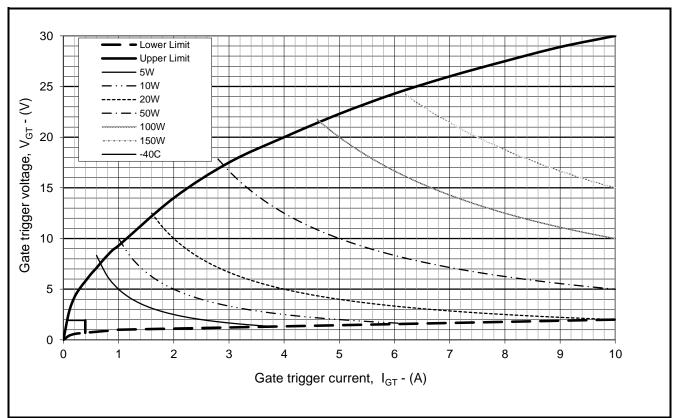


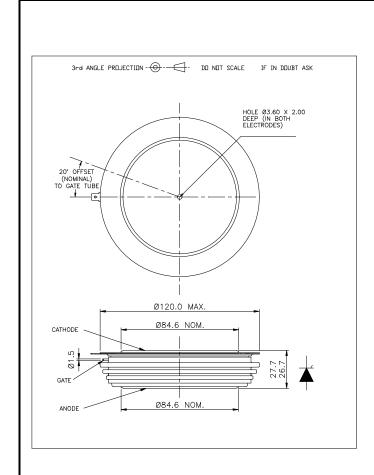
Fig. 13 Gate characteristics





PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



	N 41 1
Maximum	Minimum
Thickness	Thickness
(mm)	(mm)
27.34	26.79
27.57	27.02
27.69	27.14
27.265	26.715
27.34	26.79
27.57	27.02
27.69	27.14
27.95	27.4
28.31	27.76
	27.34 27.57 27.69 27.265 27.34 27.57 27.69 27.95

Clamping force: 76kN ±10% Lead length: 420mm Lead terminal connector: M4 ring

Package outline type code: W

Fig.14 Package outline







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